# Transm ission properties of left-handed band-gap structures

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We analyze transm ission of electrom agnetic waves through a periodic band-gap structure consisting of slabs of a left-handed metam aterial and air. Using the elective parameters of the metam aterial derived from its microscopic structure, we study, with the help of the transferm atrix approach and by means of the nite-di erence-time-dom ain numerical simulations, the transmission properties of such a left-handed photonic crystals in a novel type of band gap associated with the zero averaged refractive index. We demonstrate that the transmission can be made tunable by introducing defects, which allow to access selectively two di erent types of band gaps.

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#### I. IN TRODUCTION

M aterials with both negative dielectric perm ittivity and negative m agnetic perm eability were suggested theoretically a long time ago [1], and they are term ed leffhanded m aterials because the wave vector and Poynting vector lie in the opposite directions. M any unusual properties of such m aterials can be associated with their negative refractive index, as was dem onstrated by several reliable experiments [2, 3] and numerical nite-di erencetim e-dom ain (FDTD) simulations (see, e.g., Ref. [4]).

Multilayered structures that include materials with negative refraction can be considered as a sequence of at lenses that provide an optical cancellation of the the layers with positive refractive index leading to either enhanced or suppressed transm ission [5, 6, 7]. More im portantly, a one-dim ensional stack of layers with alternating positive and negative-refraction m aterials with zero averaged refractive index displays a novel type of the transm ission band gap [6, 8, 9, 10, 11] near the frequency where the condition  $\langle n \rangle = 0$  is satis ed; such a novel band gap is quite di erent from a conventional B ragg re ection gap because it appears due to com pletely di erent physics of wave re ection. In particular, the periodic structures with zero averaged refractive index dem onstrate a num ber of unique properties of the beam transmission observed as strong beam modi cation and reshaping [8] being also insensitive to disorder that is symmetric in the random variable [9].

In this paper, we study both transm ission properties and defect-induced tunability of the left-handed photonic band gap structures created by alternating slabs of positive and negative refractive index materials with an em – bedded defect taking into account realistic parameters, dispersion and boses of the left-handed material. We consider a band-gap structure schematically shown in Fig.1. First, we study the properties of the left-handed material as a composite structure made of arrays of wires and split-ring resonators (see the insert in Fig.1) and derive the general results for the elective dielectric per-

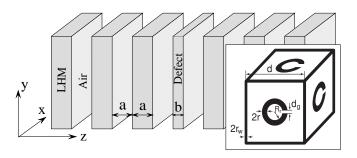


FIG.1: Schem atic of a multilayered structure consisting of alternating m etam aterial slabs and air. The inset shows the unit cell of the m etam aterial structure.

m ittivity and magnetic permeability. Second, we study the transmission of electrom agnetic waves through the layered structure consisting of alternating slabs of com posite left-handed m etam aterial using the calculated effective parameters. We assume that the structure includes a defect layer (see Fig. 1) that allows tunability of the transm ission near the defect frequency. U sing the transfer-m atrix m ethod, we describe the defect-induced localized states in such a structure and revealthat the defectm odesm ay appear in di erent param eter regions and for both  $\langle n \rangle = 0$  and Bragg scattering band gaps. Depending on the defect parameters, the maximum transm ission can be observed in allor just som e spectralband gaps of the structure. We dem on strate that the frequency of the defect m ode is less sensitive to m anufacturing disorder for the larger defect layer. Finally, we perform two-dimensional FDTD numerical simulations based on the microscopic parameters of the left-handed material and study the tem poralevolution of the transm itted and re ected elds.

## II. M ETAM ATER IAL CHARACTER IST ICS

W e assume that the left-handed m etam aterial is created by a three-dim ensional lattice of w ires and splitring resonators (SRRs), as shown in the inset of Fig. 1. A coording to the results of the derivation presented in Refs. [12, 13], the main contribution to the e ective dielectric permittivity of this structure is given by the w ires, whereas the magnetic response is determ ined by SRRs. Although a three-dim ensional lattice of w ires contains closed circuits, we neglect their contribution to the magnetic permeability, because this e ect is nonresonant, and, therefore, is weak. The e ective dielectric permittivity can be obtained in the form [12, 13]

$$(!) = 1 \frac{!_{p}^{2}}{!(! \pm )};$$
 (1)

where  $!_p$  (c=d)  $[2 = \ln (d=r_w)]^{1=2}$  is the elective plasm a frequency,  $= c^2 = 2 \text{ S ln} (d=r_w)$ , is the wire conductivity, S is the elective cross-section of a wire,  $S = \frac{r_w}{r_w}$ , for  $\geq \frac{r_w}{2}$ , and S (2r), for  $<_w r_w$  where  $= c = \frac{2}{2}$ ! is the skin-layer thickness.

To calculate the e ective magnetic permeability of the lattice of SRRswewrite its magnetization M in the form (see also Ref. [14])

$$M = (n_m = 2c) R_r^2 I_r;$$
 (2)

where  $n_m = 3=d^3$  is the number of SRRs per unit cell, R<sub>r</sub> is the SRR radius (see the insert in Fig. 1), I<sub>r</sub> is the current in the SRR. We assume that SRR is an e ective oscillatory circuit with inductance L and resistance R of the wire, and capacity C of the SRR slot. In this circuit the electrom otive force in this circuit due to an alternating m agnetic eld of the propagating wave. Under these assumptions, the evolution of the current I<sub>r</sub> in single SRR is governed by the equation

$$L\frac{d^{2}I_{r}}{dt^{2}} + R\frac{dI_{r}}{dt} + \frac{1}{C}I_{r} = \frac{dE}{dt};$$
(3)

with

$$E = \frac{R_r^2}{C} \frac{dH^0}{dt};$$

where  $H^{0}$  is the acting (m icroscopic) magnetic eld, which di ers from the average (m acroscopic) magnetic

eld. We describe the SRR array as a system of magnetic dipoles, which is valid when the number of SRRs in the volum e  $^3$  is big enough, and use the Lorenz-Lorentz relation between the m icroscopic and m acroscopic m agnetic elds [15]

$$H^{0} = H + \frac{4}{3}M = B - \frac{8}{3}M :$$
 (4)

As a result, from Eqs. (2) { (4) we obtain the e ective magnetic permeability of the structure in the form,

$$(!) = 1 + \frac{F!^{2}}{!^{2}_{0} !^{2} (1 + F = 3) + i!};$$
(5)

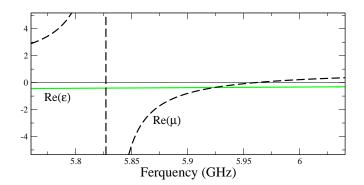


FIG.2: Frequency dependence of the real part of the dielectric perm ittivity Re() (solid), and the real part of magnetic perm eability Re()(dashed).

where  $F = 2 n_m$  ( $R_r^2 = c)^2 = L$ ,  $!_0^2 = 1 = LC$ , and = R = L. Inductance L, resistance R, and capacitance C are given by the following results (see, e.g., Ref. [16]),

$$L = \frac{4 R_{r}}{c^{2}} \ln \frac{8R_{r}}{r} - \frac{7}{4} ; R = \frac{2 R_{r}}{S_{r}}; C = \frac{r^{2}}{4 d_{g}};$$

where r is the radius of the wire that m akes a ring, is conductivity of the wire,  $S_r$  is the elective area of the cross-section of SRR wire de ned similar to that of a straight wire, and  $d_g$  is the size of the SRR slot. We note, that the result for C should hold provided  $d_q$  r.

Taking the parameters of a metallic composite as d=1 cm,  $r_w$  = 0.05 cm,  $R_r$  = 0.2 cm, r = 0.02 cm,  $d_g$  = 10 $^3$  cm, and its conductivity as = 2 $1^{10}$  s $^1$ , we calculate the elective frequency dependencies of (!) and

(!) according to Eqs. (1) and (5), respectively, and show these dependencies in Fig. 2. The resonance frequency appears near 5.82 GHz, and the region of simultaneously negative and is between 5.82 GHz and 5.96 GHz. The imaginary part of the magnetic permeability, which determ ines e ective losses in a left-handed material, is larger near the resonance.

## III. TRANSM ISSION AND DEFECT MODES

W e consider now a band gap structure created by seven alternating left-handed and dielectric slab pairs, as shown in F ig. 1. The number of slabs is chosen to keep losses in the structure at a reasonably low level, still having visible the e ects of periodicity. We assume that the periodic structure is created by slabs of the width a, m ade of the left-handed com posite described above, and separated by air ( $_a = 1$ ,  $_a = 1$ ). The m iddle layer of the left-handed m aterial is assumed to have a di erent thickness, b = a(1 + ), in order to describe a structural defect.

To study the transmission characteristics of such a band-gap structure, we consider a normal-incidence plane wave for the scalar electric eld described by the Helm holtz-type equation,

$$\frac{d^2}{dz^2} + \frac{!^2}{c^2} (z) (z) - \frac{1}{(z)} \frac{d}{dz} \frac{d}{dz} E = 0; \quad (6)$$

where (z) and (z) are the dielectric perm ittivity and magnetic perm eability in the whole space.

Before analyzing the transm ission properties of a nite layered structure, rst we study the corresponding in – nite structure without defects and calculate its band gap spectrum. In an in nite periodic structure, propagating waves in the form of the F bquet-B bch m odes satisfy the periodicity condition, E (z + 2a) = E (z) exp (2ia K b), where K b is the B bch wavenum ber. The values of K b are found as solutions of the standard eigenvalue equation for a two-layered periodic structure (see, e.g., Ref. [11]),

$$2\cos(K_{b}2a) = 2\cos[(k_{r} + k_{l})a]$$

$$\frac{p_{r}}{p_{l}} + \frac{p_{l}}{p_{r}} - 2\sin(k_{a}) \sin(k_{a}); \quad (7)$$

where  $p_r = 1, p_1 = {p - r \choose r}, k_r = ! = c \text{ and } k_1 = ! = c {p - r \choose r}$  are the wavevectors in air and left-handed slabs, respectively. For real values of K b, the B loch waves are propagating; com plex values of K b indicate the presence of band gaps, where the wave propagation is suppressed. The spectral gaps appear when the argument of the cosine function in Eq. (7) becomes the whole multiple of , and no real solutions for K<sub>b</sub> exist. These gaps are usually term ed as Bragg gaps. The presence of the left-handed material in the structure makes it possible for the argument to vanish, so that the wave propagation becom es prohibited in this case as well, thus creating an additional band gap, which do not exist in conventional periodic structures. As a matter of fact, the condition  $k_r j = k_1 j$  corresponds to the zero average refractive index,  $\langle n \rangle = 0$ , as discussed in Refs. [6, 8, 9, 10, 11]. However, the inherent feature of the left-handed m aterials is their frequency dispersion, so that the condition  $k_r j = k_1 j de$  nes a characteristic frequency ! at which the indices of refraction in both the media compensate each other. In a sharp contrast to the conventional Bragg re ection gaps, the position of this additional  $\langle n \rangle = 0$  gap in the frequency domain does not depend on the optical period of the structure.

For the param eters of the left-handed m edia described above, the frequency ! at which the average refractive index vanishes is found as ! 2 5:8636 °10s ¹. Importantly, the transmission coe cient calculated at ! = ! for the seven-layer structure shows a characteristic resonant dependence as a function of the norm alized slab thickness a =, where = 2 c = !, as shown in Fig. 3. The transmission maxim a appear in the  $\langle n \rangle = 0$  gap, when the slab thickness a coincides with a whole multiple of a half of the wavelength. The width of the transmission peaks decreases with the increase of the number of layers in the structure. The transmission maxim a decrease with increasing thickness of the structure due to losses in the left-handed m aterial which become larger for thicker slabs. One of the interesting features of the  $\langle n \rangle = 0$ 

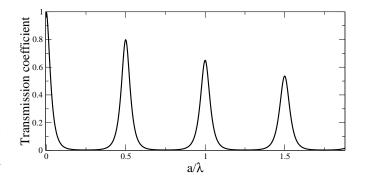


FIG.3: Transm ission coe cient of a nite periodic structure with seven layers of left-handed material vs. the norm alized slab thickness a= , where = 2 c=! and the frequency ! = ! corresponds to the condition < n > = 0.

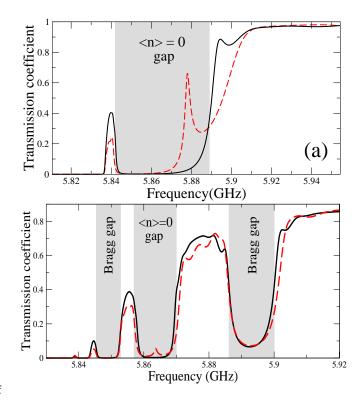


FIG.4: Transm ission coe cient of the left-handed band-gap structure vs. the wave frequency. (a) The structure with the period a = 0.25, without (solid) and with (dashed) defect layer (= 0.8). (b) The structure with the period a = 1.25 without (solid) and with (dashed) defect layer (= 0.6).

gap is that the transm ission coe cient can vanish even for very small values of the slab thickness. This property can be employed to create e ective m irrors in the m icrowave region operating in this novel < n > = 0 gap which can be e ectively thinner than the wavelength of electrom agnetic waves.

The transmission coe cient is shown in Fig. 4 (a,b) as a function of the frequency, for two structures with different values of the period a. For the quarter-wavelength

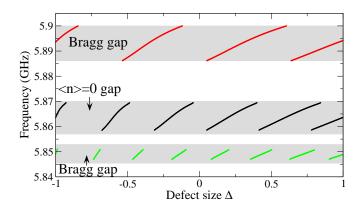


FIG. 5: Frequency spectrum of the defect modes as a function of the normalized defect size in the left-handed band-gap structure with the period a = 1.25.

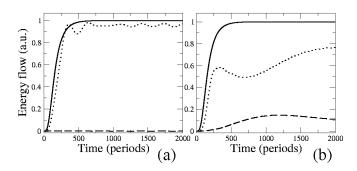


FIG.6: Numerical FDTD simulation results showing relaxation processes in a band-gap structure with a defect. Solid { incident energy ow, dashed { transmitted energy ow, dotted { re ected energy ow.Parameters are: a = 0.25, = 0.8. (a) D effect mode is not excited,  $! = 25.86 \quad 10^9 \text{ s}^{-1}$ ; (b) D efect mode is excited,  $! = 25.878 \quad 10^9 \text{ s}^{-1}$ .

slabs [see Fig. 4(a)], the only visible band gap is the  $\langle n \rangle = 0$  gap centered near ! where both and are negative. W hen the structure has a defect, the transm ission peak associated with the excitation of the defect m ode appears inside the  $\langle n \rangle = 0$  gap as shown by the dashed curve. For the structure with thicker slabs, e.g. for a = 1.25 [see Fig. 4(b)] the  $\langle n \rangle = 0$  gap becom es narrow er but it rem ains centered near the frequency ! . The transmission coe cient of this second band-gap structure shows, in addition to the  $\langle n \rangle = 0$ gap, two Bragg scattering gaps. Due to the increased losses in this second band-gap structure, where slabs are thicker than in the structure corresponding to F ig. 4 (a), the e ects of the resonant transmission at the defect m ode becom e less visible. M oreover, for the param eters we consider here the defect mode appears only in the  $\langle n \rangle = 0$  gap, whereas it does not appear in the B ragg gaps. For larger slab thickness, higher-order B ragg gaps m ay appear in the frequency range where the composite m aterial is left-handed.

In Fig.5, we show the frequency spectrum of the defect modes for the structure with a = 1.25 as a function of the norm alized defect size . We notice a number of

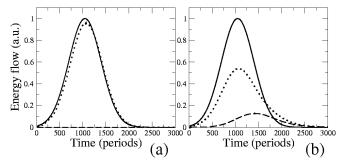


FIG.7: Numerical FDTD simulation results for the pulse scattering by a periodic structure with defect. Solid { incident energy ow, dashed { transmitted energy ow, dotted { re ected energy ow.Parameters are: a = 0.25, = 0.8. (a) D effect m ode is not excited,  $! = 25.86 \ 10^9 \ s^1$ ; (b) D effect m ode is excited,  $! = 25.878 \ 10^9 \ s^1$ .

in portant features: (i) the defect modes do not always appear simultaneously in allgaps, and (ii) the slope of the curves in Fig. 5 decreases with the growth of the defect thickness. As a result, the eigenfrequencies of the modes introduced by thicker defect layers can be more stable to disorder introduced by manufacturing. These novel features seem to be important for tunable properties of the layered structures because the di erent modes allow to access di erent types of band gaps.

#### IV. NUMERICAL FDTD SIMULATIONS

In order to analyze the tem poral evolution of the transmitted elds and the beam scattering under realistic conditions, we perform two-dimensional FDTD numerical simulations of the beam propagation through the lefthanded periodic structure of seven layers with a defect. We consider TM -polarized Gaussian beam of the width 20 propagating towards the structure with the period a = 0.25; such a structure corresponds to the transmission coe cient shown in Fig. 4(a) by a dashed line. First, we choose the frequency of the incident eld in the  $\langle n \rangle = 0$  gap. The tem poral evolution of the energy ows (integrated over the transverse dim ension) for the incident, transmitted, and re ected waves is shown in Fig. 6(a), clearly indicating that the transmission through such a structure is negligible. W hen the frequency of the incident eld coincides with that of the defectm ode, a signi cant am ount of the energy is transm itted through the structure [see Fig. 6(b)]. The relaxation time of the beam transmission through the structure is estim ated as  $10^3$  periods (approxim ately 170 ns).

Results of FD TD simulations for the pulse scattering from the structure with a = 0.25 are shown in Figs. 7 (a,b) as the temporal dependence of the incident, re-

ected and transmitted energy ows. One can clearly see signi cant transmission, when the carrier frequency of the pulse coincides with the eigen frequency of the defect mode [see Figs. 7 (a,b)].

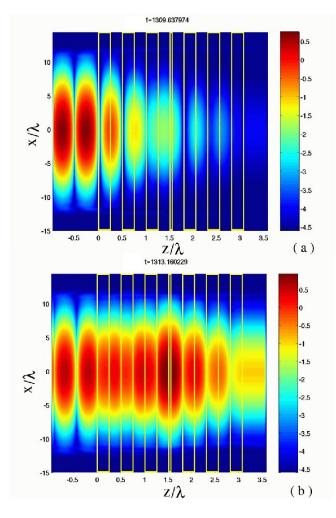


FIG.8: Results of the numerical FDTD simulations for the amplitude of the magnetic eld in a two-dimensional structure (natural logarithm scale). Boxes show positions of the left-handed slabs, a = 0.25, = 0.8. (a) Defect mode is not excited,  $! = 25.86 \quad 10^9 \text{ s}^{-1}$ ; (b) Defect mode is excited,  $! = 25.878 \quad 10^9 \text{ s}^{-1}$ .

An example of the eld distribution in the structure with the slab size a = 0.25 is shown in Figs. 8 (a,b) for two di erent regimes. In Fig. 8 (a), the frequency corresponds to low transmission in Fig. 4 (a), when no defect mode is excited. Figure 8 (b) demonstrates the eld distribution in the structure with an excited defect

m ode and enhanced transm ission.

## V. CONCLUSIONS

W e have studied the transm ission properties of periodic structures m ade of a left-handed m etam aterial and air. U sing realistic param eters of the m etam aterial derived from the microscopic approach, we have calculated the band-gap spectrum of an in nite one-dimensional structure with and without defects, demonstrating the existence of band gaps of two di erent types, the conventional B ragg scattering gaps and a novel  $\langle n \rangle = 0$  gap. W e have analyzed the properties of the defect m odes in nite periodic structure with a structural defect and а dem onstrated that, depending on the defect size, the defect modes appear in all or just som e of the band gaps allowing to access di erent gaps selectively. In addition, we have perform ed two-dim ensional num erical FDTD sim ulations of the propagation of electrom agnetic waves in such structures and have studied the tem poral dynam ics of the beam transmission and re ection. We have dem onstrated that the excitation of defect modes can enhance substantially the wave transmission through the structure.

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- [L] V.G. Veselago, Usp. Fiz. Nauk 92, 517 (1967) (in Russian) Phys. Usp. 10, 509 (1968)].
- [2] R.A. Shelby, D.R. Sm ith, and S. Schultz, Science 292, 77 (2001).
- [3] C.G. Parazzoli, R.B.G reegor, K.Li, B.E.C.Koltenbah, and M. Tanielian, Phys. Rev. Lett. 90, 107401 (2003).
- [4] S.Foteinopoulou, E.N. Econom ou, and C.M. Soukoulis, Phys. Rev. Lett. 90, 107402 (2003).
- [5] J.B. Pendry and S.A. Ram akrishna, J. Phys. Condens. M atter 15, 6345 (2003).
- [6] I. S. Nefedov and S. A. Tretyakov, Phys. Rev. E 66, 036611 (2002).
- [7] Z.M. Zhang and C.J.Fu, Appl. Phys. Lett. 80, 1097 (2002).
- [8] I.V. Shadrivov, A.A. Sukhonukov, and Yu.S.K ivshar, Appl. Phys. Lett. 82, 3820 (2003).
- [9] J. Li, L. Zhou, C. T. Chan, and P. Sheng, Phys. Rev.

Lett.90,083901 (2003).

- [10] R.Ruppin, Microw.Opt.Technol.Lett. 38, 494 (2003).
- [11] L.W u, S.L.He, and L.F.Shen, Phys.Rev.B 67, 235103 (2003).
- [12] J.B.Pendry, A.J.Holden, W.J.Stewart, and I.Youngs, Phys. Rev. Lett. 76, 4773 (1996).
- [13] A.A.Zharov, I.V.Shadrivov, and Yu.S.K ivshar, Phys. Rev.Lett. 91, 037401 (2003).
- [14] J. B. Pendry, A. J. Holden, D. J. Robbins, and W. J. Stewart, EEE Trans. M icrow. Theory Tech. 47, 2075 (1999).
- [15] L. D. Landau and E. M. Lifshitz, Electrodynamics of Continuous M edia (Pergam on Press, Oxford, 1963).
- [16] J. Schwinger, Classical Electrodynamics (Perseus Books, Reading, Mass., 1998).